

## FEATURES

- **Guaranteed Low Offset Voltage**

LT1001AM	15 $\mu$ V max
LT1001C	60 $\mu$ V max
- **Guaranteed Low Drift**

LT1001AM	0.6 $\mu$ V/ $^{\circ}$ C max
LT1001C	1.0 $\mu$ V/ $^{\circ}$ C max
- **Guaranteed Low Bias Current**

LT1001AM	2nA max
LT1001C	4nA max
- **Guaranteed CMRR**

LT1001AM	114dB min
LT1001C	110dB min
- **Guaranteed PSRR**

LT1001AM	110dB min
LT1001C	106dB min
- **Low Power Dissipation**

LT1001AM	75mW max
LT1001C	80mW max
- **Low Noise 0.3 $\mu$ V<sub>P-P</sub>**

## APPLICATIONS

- Thermocouple amplifiers
- Strain gauge amplifiers
- Low level signal processing
- High accuracy data acquisition

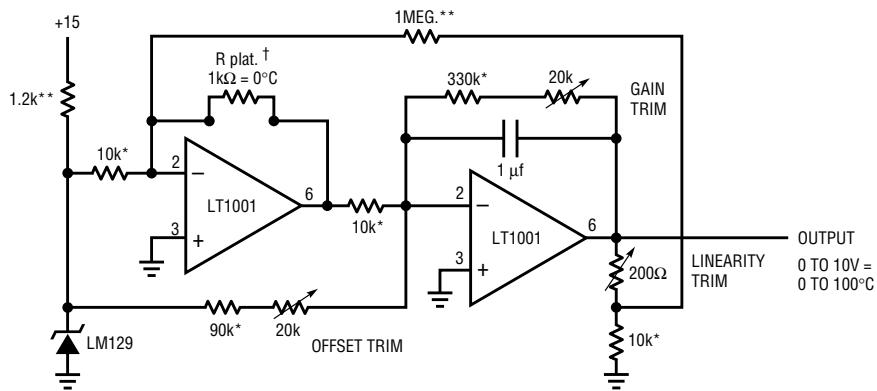
## DESCRIPTION

The LT®1001 significantly advances the state-of-the-art of precision operational amplifiers. In the design, processing, and testing of the device, particular attention has been paid to the optimization of the entire distribution of several key parameters. Consequently, the specifications of the lowest cost, commercial temperature device, the LT1001C, have been dramatically improved when compared to equivalent grades of competing precision amplifiers.

Essentially, the input offset voltage of all units is less than 50 $\mu$ V (see distribution plot below). This allows the LT1001AM/883 to be specified at 15 $\mu$ V. Input bias and offset currents, common-mode and power supply rejection of the LT1001C offer guaranteed performance which were previously attainable only with expensive, selected grades of other devices. Power dissipation is nearly halved compared to the most popular precision op amps, without adversely affecting noise or speed performance. A beneficial by-product of lower dissipation is decreased warm-up drift. Output drive capability of the LT1001 is also enhanced with voltage gain guaranteed at 10 mA of load current. For similar performance in a dual precision op amp, with guaranteed matching specifications, see the LT1002. Shown below is a platinum resistance thermometer application.

 LTC and LT are registered trademarks of Linear Technology Corporation.

**Linearized Platinum Resistance Thermometer  
with  $\pm 0.025^{\circ}$ C Accuracy Over 0 to 100 $^{\circ}$ C**



\* ULTRONIX 105A WIREWOUND

\*\* 1% FILM

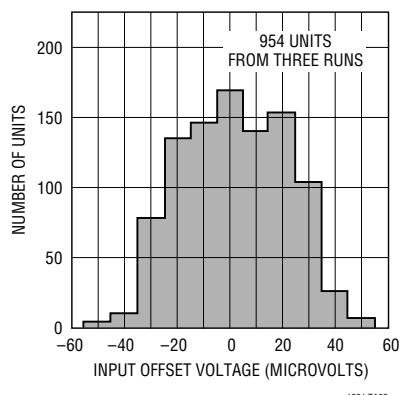
† PLATINUM RTD

118MF (ROSEMOUNT, INC.)

‡ Trim sequence: trim offset ( $0^{\circ}$ C = 1000.0 $\Omega$ ), trim linearity ( $35^{\circ}$ C = 1138.7 $\Omega$ ), trim gain ( $100^{\circ}$ C = 1392.6 $\Omega$ ). Repeat until all three points are fixed with  $\pm 0.025^{\circ}$ C.

1001 TA01

**Typical Distribution  
of Offset Voltage  
 $V_S = \pm 15V, T_A = 25^{\circ}$ C**



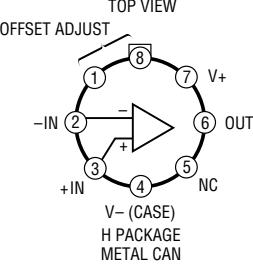
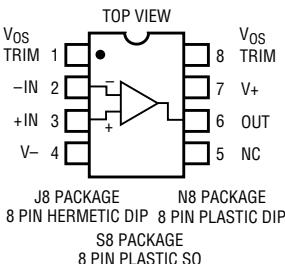
1001 TA02

# LT1001

## ABSOLUTE MAXIMUM RATINGS

Supply Voltage .....	$\pm 22\text{V}$
Differential Input Voltage .....	$\pm 30\text{V}$
Input Voltage .....	$\pm 22\text{V}$
Output Short Circuit Duration .....	Indefinite
Operating Temperature Range	
LT1001AM/LT1001M .....	-55°C to 150°C
LT1001AC/LT1001C .....	0°C to 125°C
Storage: All Devices .....	-65°C to 150°C
Lead Temperature (Soldering, 10 sec.) .....	300°C

## PACKAGE/ORDER INFORMATION

TOP VIEW	ORDER PART NUMBER
	LT1001AMH/883 LT1001MH LT1001ACH LT1001CH
	LT1001AMJ8/883 LT1001MJ8 LT1001ACJ8 LT1001CJ8 LT1001ACN8 LT1001CN8 LT1001CS8
	S8 PART MARKING 1001

## ELECTRICAL CHARACTERISTICS $V_S = \pm 15\text{V}$ , $T_A = 25^\circ\text{C}$ , unless otherwise noted

SYMBOL	PARAMETER	CONDITIONS	LT1001AM/883			LT1001AC			LT1001M/LT1001C	UNITS
			MIN	TYP	MAX	MIN	TYP	MAX		
$V_{OS}$	Input Offset Voltage	Note 1 LT1001AM/883	7	15					18	$\mu\text{V}$
		LT1001AC	10	25						
$\Delta V_{OS}$ $\Delta T$	Long Term Input Offset Voltage Stability	Notes 2 and 3		0.2	1.0			0.3	1.5	$\mu\text{V}/\text{month}$
$I_{OS}$	Input Offset Current			0.3	2.0			0.4	3.8	$\text{nA}$
$I_b$	Input Bias Current			$\pm 0.5$	$\pm 2.0$			$\pm 0.7$	$\pm 4.0$	$\text{nA}$
$e_n$	Input Noise Voltage	0.1Hz to 10Hz (Note 2)		0.3	0.6			0.3	0.6	$\mu\text{V}_{\text{p-p}}$
$e_n$	Input Noise Voltage Density	$f_0 = 10\text{Hz}$ (Note 5) $f_0 = 1000\text{Hz}$ (Note 2)		10.3	18.0			10.5	18.0	$\text{nV}\sqrt{\text{Hz}}$
$A_{VOL}$	Large Signal Voltage Gain	$R_L \geq 2\text{k}\Omega$ , $V_0 = \pm 12\text{V}$	450	800		400	800		V/mV	
		$R_L \geq 1\text{k}\Omega$ , $V_0 = \pm 10\text{V}$	300	500		250	500			
CMRR	Common Mode Rejection Ratio	$V_{CM} = \pm 13\text{V}$	114	126		110	126			dB
PSRR	Power Supply Rejection Ratio	$V_S = \pm 3\text{V}$ to $\pm 18\text{V}$	110	123		106	123			dB
$R_{in}$	Input Resistance Differential Mode		30	100		15	80		$\text{M}\Omega$	
		Input Voltage Range	$\pm 13$	$\pm 14$		$\pm 13$	$\pm 14$			
$V_{OUT}$	Maximum Output Voltage Swing	$R_L \geq 2\text{k}\Omega$	$\pm 13$	$\pm 14$		$\pm 13$	$\pm 14$		V	
		$R_L \geq 1\text{k}\Omega$	$\pm 12$	$\pm 13.5$		$\pm 12$	$\pm 13.5$			
$S_R$	Slew Rate	$R_L \geq 2\text{k}\Omega$ (Note 4)	0.1	0.25		0.1	0.25			$\text{V}/\mu\text{s}$
GBW	Gain-Bandwidth Product	(Note 4)	0.4	0.8		0.4	0.8			MHz
$P_d$	Power Dissipation	No load	46	75		48	80		mW	
		No load, $V_S = \pm 3\text{V}$	4	6		4	8			

See Notes on page 3.

## ELECTRICAL CHARACTERISTICS $V_S = \pm 15V, -55^\circ C \leq T_A \leq 125^\circ C$ , unless otherwise noted

SYMBOL	PARAMETER	CONDITIONS	LT1001AM/883			LT1001M			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
$V_{OS}$	Input Offset Voltage		●	30	60	45	160	μV	
$\Delta V_{OS}$	Average Offset Voltage Drift		●	0.2	0.6	0.3	1.0	μV/°C	
$\Delta T_{Temp}$									
$I_{OS}$	Input Offset Current		●	0.8	4.0	1.2	7.6	nA	
$I_B$	Input Bias Current		●	±1.0	±4.0	±1.5	±8.0	nA	
$A_{VOL}$	Large Signal Voltage Gain	$R_L \geq 2k\Omega, V_0 = \pm 10V$	●	300	700	200	700	V/mV	
CMRR	Common Mode Rejection Ratio	$V_{CM} = \pm 13V$	●	110	122	106	120	dB	
PSRR	Power Supply Rejection Ratio	$V_S = \pm 3$ to $\pm 18V$	●	104	117	100	117	dB	
	Input Voltage Range		●	±13	±14	±13	±14	V	
$V_{OUT}$	Output Voltage Swing	$R_L \geq 2k\Omega$	●	±12.5	±13.5	±12.0	±13.5	V	
$P_d$	Power Dissipation	No load	●	55	90	60	100	mW	

$V_S = \pm 15V, 0^\circ C \leq T_A \leq 70^\circ C$ , unless otherwise noted

SYMBOL	PARAMETER	CONDITIONS	LT1001AC			LT1001C			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
$V_{OS}$	Input Offset Voltage		●	20	60	30	110	μV	
$\Delta V_{OS}$	Average Offset Voltage Drift		●	0.2	0.6	0.3	1.0	μV/°C	
$\Delta T_{Temp}$									
$I_{OS}$	Input Offset Current		●	0.5	3.5	0.6	5.3	nA	
$I_B$	Input Bias Current		●	±0.7	±3.5	±1.0	±5.5	nA	
$A_{VOL}$	Large Signal Voltage Gain	$R_L \geq 2k\Omega, V_0 = \pm 10V$	●	350	750	250	750	V/mV	
CMRR	Common Mode Rejection Ratio	$V_{CM} = \pm 13V$	●	110	124	106	123	dB	
PSRR	Power Supply Rejection Ratio	$V_S = \pm 3V$ to $\pm 18V$	●	106	120	103	120	dB	
	Input Voltage Range		●	±13	±14	±13	±14	V	
$V_{OUT}$	Output Voltage Swing	$R_L \geq 2k\Omega$	●	±12.5	±13.8	±12.5	±13.8	V	
$P_d$	Power Dissipation	No load	●	50	85	55	90	mW	

The ● denotes the specifications which apply over the full operating temperature range.

**Note 1:** Offset voltage for the LT1001AM/883 and LT1001AC are measured after power is applied and the device is fully warmed up. All other grades are measured with high speed test equipment, approximately 1 second after power is applied. The LT1001AM/883 receives 168 hr. burn-in at 125°C. or equivalent.

**Note 2:** This parameter is tested on a sample basis only.

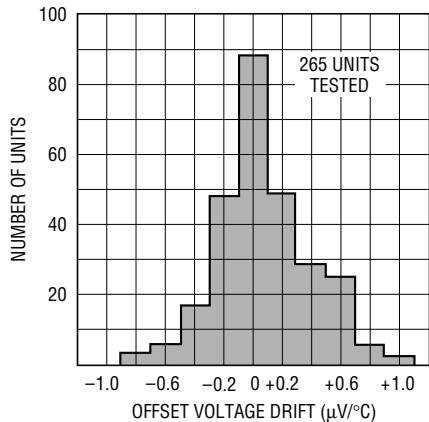
**Note 3:** Long Term Input Offset Voltage Stability refers to the averaged trend line of  $V_{OS}$  versus Time over extended periods after the first 30 days of operation. Excluding the initial hour of operation, changes in  $V_{OS}$  during the first 30 days are typically 2.5 μV.

**Note 4:** Parameter is guaranteed by design.

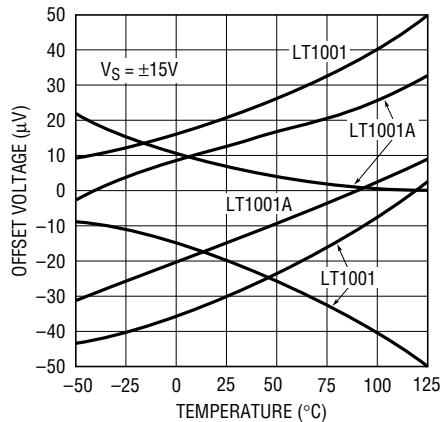
**Note 5:** 10Hz noise voltage density is sample tested on every lot. Devices 100% tested at 10Hz are available on request.

## TYPICAL PERFORMANCE CHARACTERISTICS

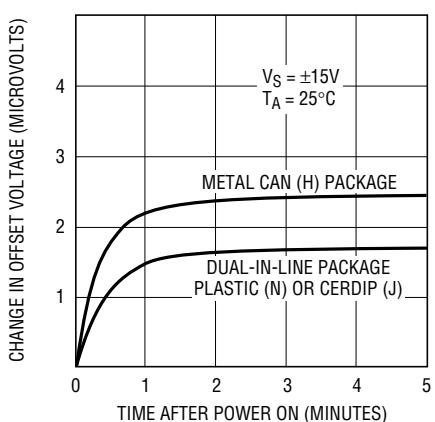
Typical Distribution of Offset Voltage Drift with Temperature



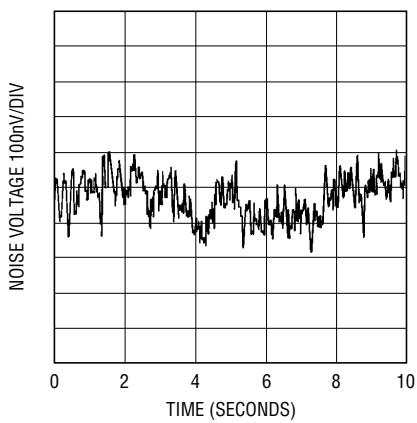
Offset Voltage Drift with Temperature of Representative Units



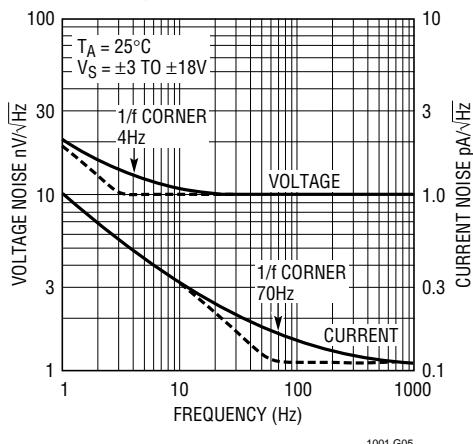
Warm-Up Drift



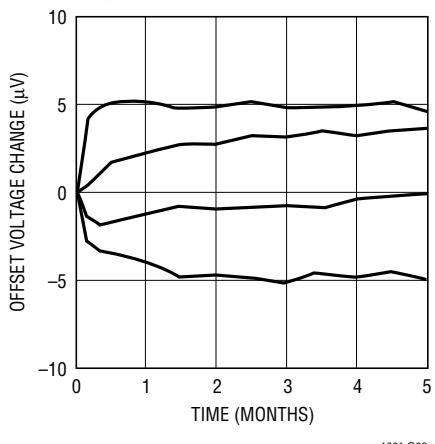
0.1Hz to 10Hz Noise



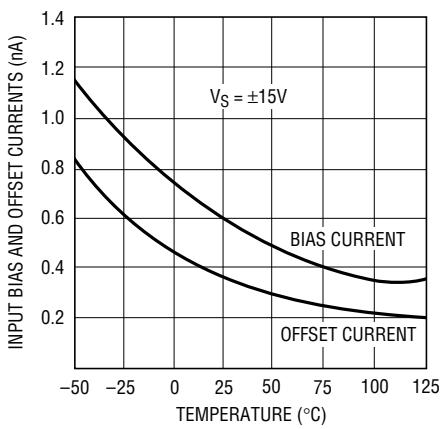
Noise Spectrum



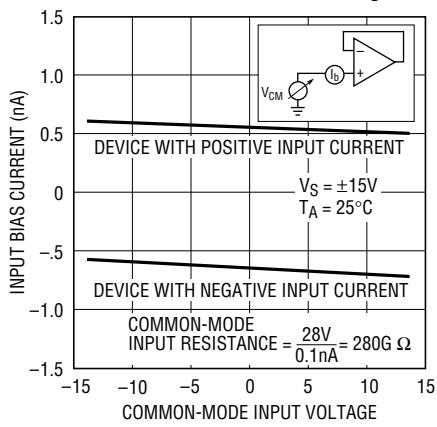
Long Term Stability of Four Representative Units



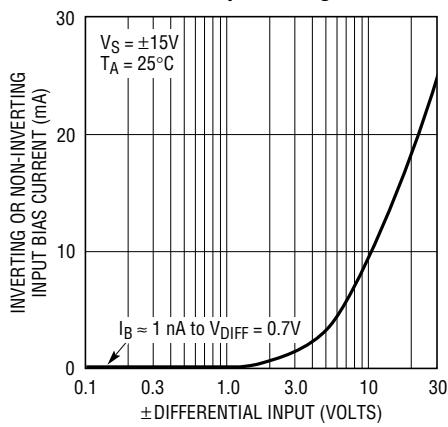
Input Bias and Offset Current vs Temperature



Input Bias Current Over the Common Mode Range

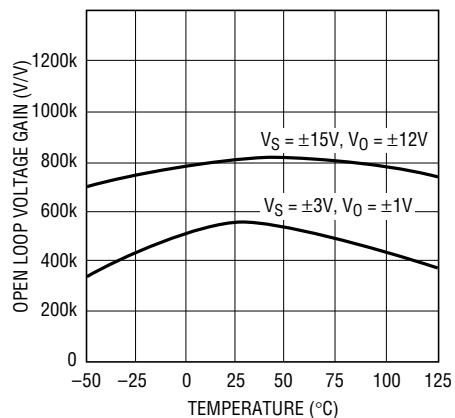


Input Bias Current vs Differential Input Voltage

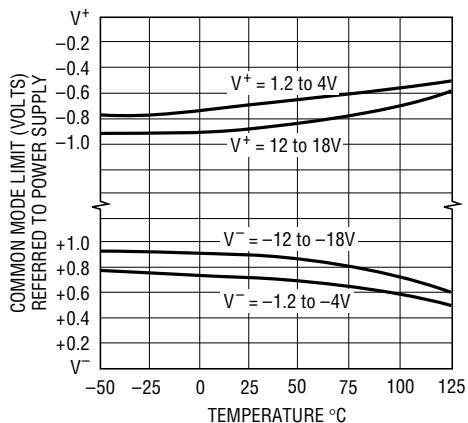


## TYPICAL PERFORMANCE CHARACTERISTICS

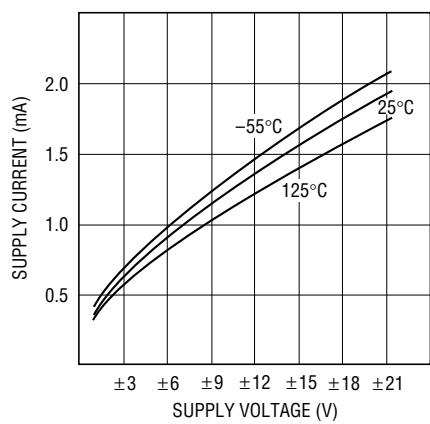
**Open Loop Voltage Gain vs Temperature**



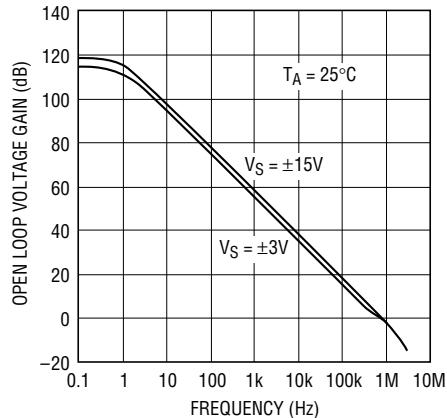
**Common Mode Limit vs Temperature**



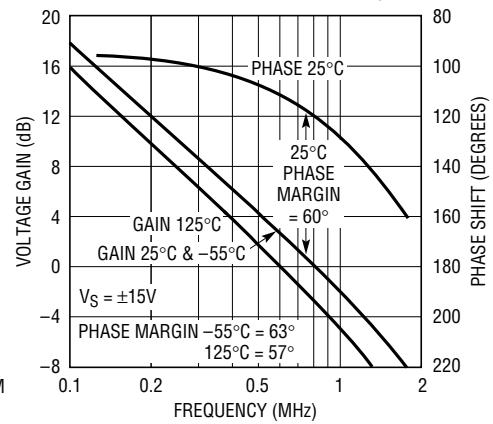
**Supply Current vs Supply Voltage**



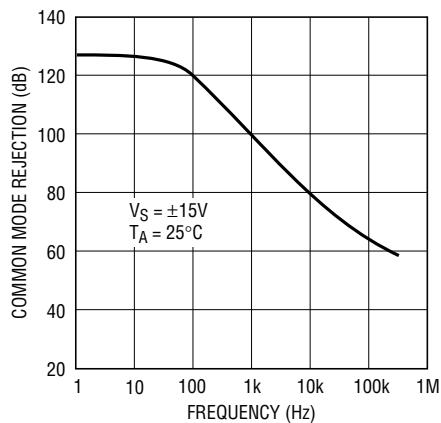
**Open Loop Voltage Gain Frequency Response**



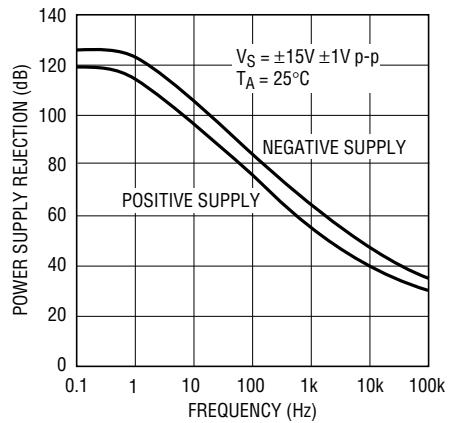
**Gain, Phase Shift vs Frequency**



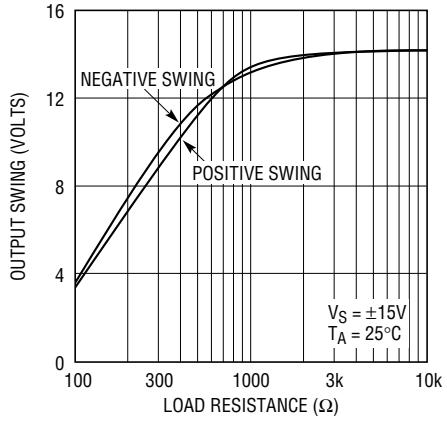
**Common Mode Rejection Ratio vs Frequency**



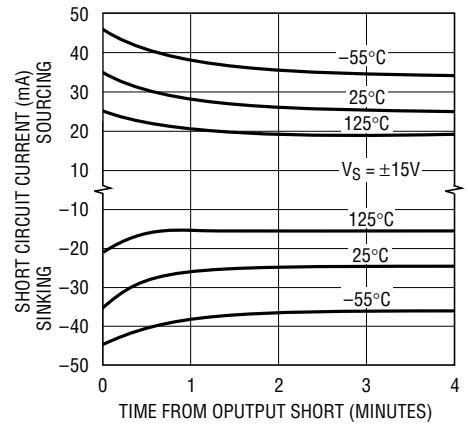
**Power Supply Rejection Ratio vs Frequency**



**Output Swing vs Load Resistance**

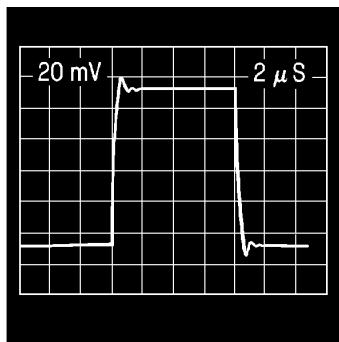


**Output Short-Circuit Current vs Time**



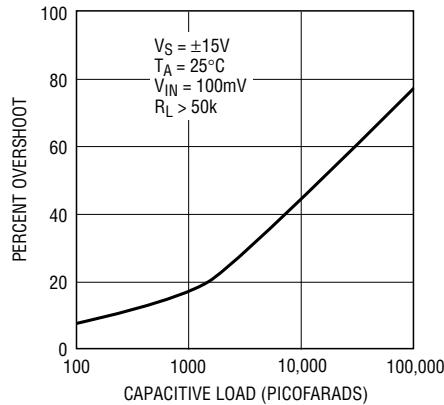
## TYPICAL PERFORMANCE CHARACTERISTICS

Small Signal Transient Response

 $A_V = +1, C_L = 50\text{pF}$ 

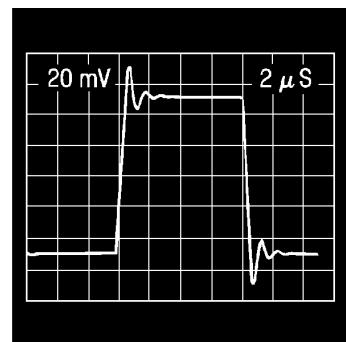
1001 G19

Voltage Follower Overshoot vs Capacitive Load



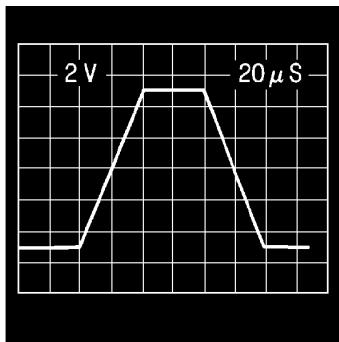
1001 G20

Small Signal Transient Response

 $A_V = +1, C_L = 1000\text{pF}$ 

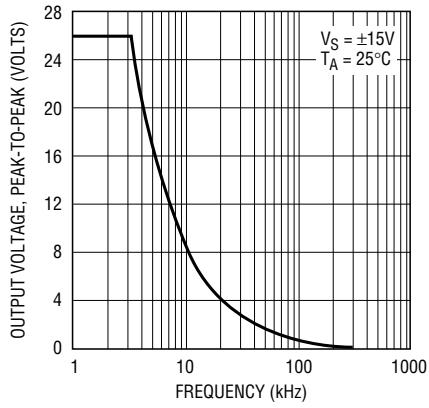
1001 G21

Large Signal Transient Response



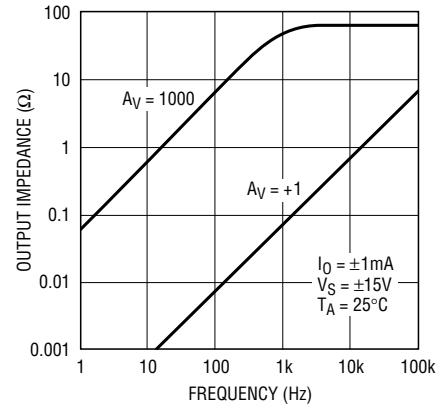
1001 G22

Maximum Undistorted Output vs. Frequency



1001 G23

Closed Loop Output Impedance



1001 G24

## APPLICATIONS INFORMATION

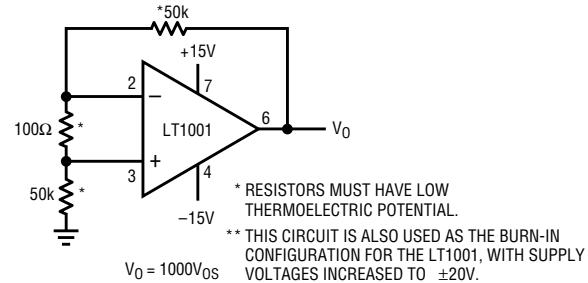
## Application Notes and Test Circuits

The LT1001 series units may be inserted directly into OP-07, OP-05, 725, 108A or 101A sockets with or without removal of external frequency compensation or nulling components. The LT1001 can also be used in 741, LF156 or OP-15 applications provided that the nulling circuitry is removed.

The LT1001 is specified over a wide range of power supply voltages from  $\pm 3\text{V}$  to  $\pm 18\text{V}$ . Operation with lower supplies is possible down to  $\pm 1.2\text{V}$  (two Ni-Cad batteries). However, with  $\pm 1.2\text{V}$  supplies, the device is stable only in closed loop gains of +2 or higher (or inverting gain of one or higher).

Unless proper care is exercised, thermocouple effects caused by temperature gradients across dissimilar metals at the contacts to the input terminals, can exceed the inherent drift of the amplifier. Air currents over device leads should be minimized, package leads should be short, and the two input leads should be as close together as possible and maintained at the same temperature.

## Test Circuit for Offset Voltage and its Drift with Temperature

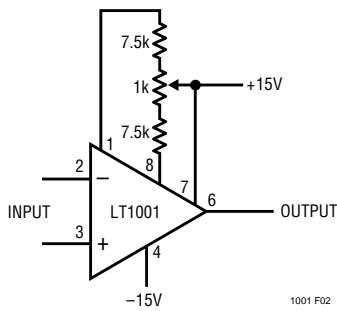


1001 F01

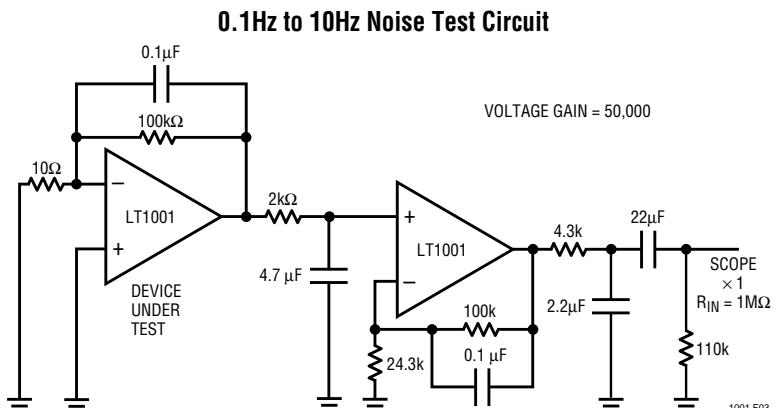
## Offset Voltage Adjustment

The input offset voltage of the LT1001, and its drift with temperature, are permanently trimmed at wafer test to a low level. However, if further adjustment of  $V_{OS}$  is necessary, nulling with a 10k or 20k potentiometer will not degrade drift with temperature. Trimming to a value other than zero creates a drift of  $(V_{OS}/300)\mu V/\text{°C}$ , e.g., if  $V_{OS}$  is adjusted to 300  $\mu V$ , the change in drift will be 1  $\mu V/\text{°C}$ . The adjustment range with a 10k or 20k pot is approximately  $\pm 2.5\text{mV}$ . If less adjustment range is needed, the sensitivity and resolution of the nulling can be improved by using a smaller pot in conjunction with fixed resistors. The example below has an approximate null range of  $\pm 100 \mu V$ .

## Improved Sensitivity Adjustment



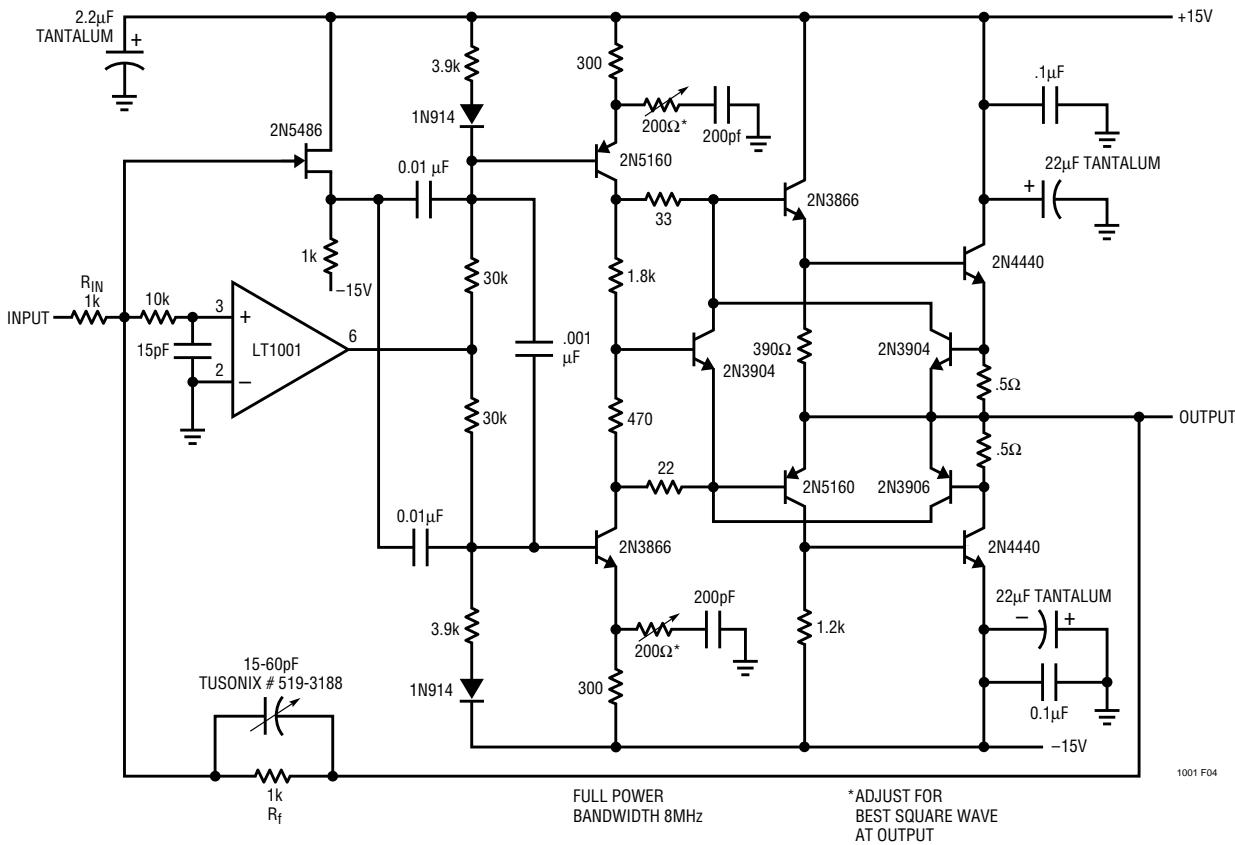
1001 F02



(Peak-to-Peak noise measured in 10 sec interval)

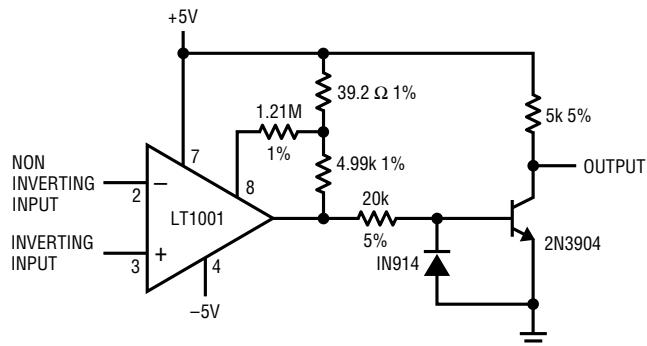
The device under test should be warmed up for three minutes and shielded from air currents.

## DC Stabilized 1000v/ $\mu$ sec Op Amp



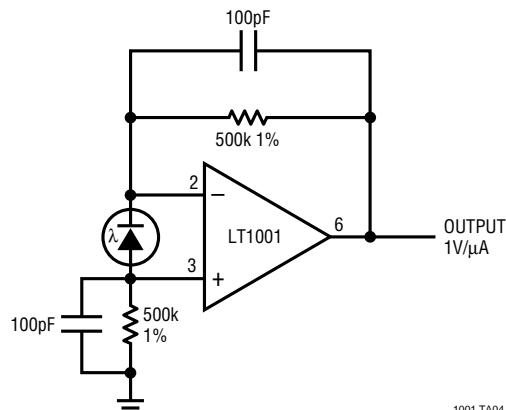
## TYPICAL APPLICATIONS

### Microvolt Comparator with TTL Output



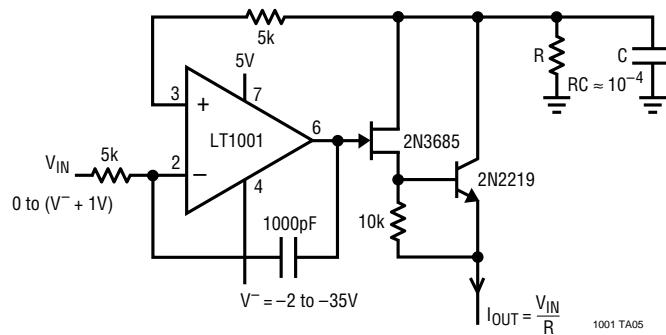
Positive feedback to one of the nulling terminals creates 5  $\mu$ V to 20  $\mu$ V of hysteresis. Input offset voltage is typically changed by less than 5  $\mu$ V due to the feedback.

### Photodiode Amplifier



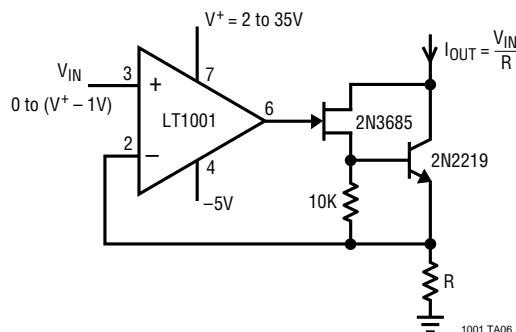
1001 TA04

### Precision Current Source



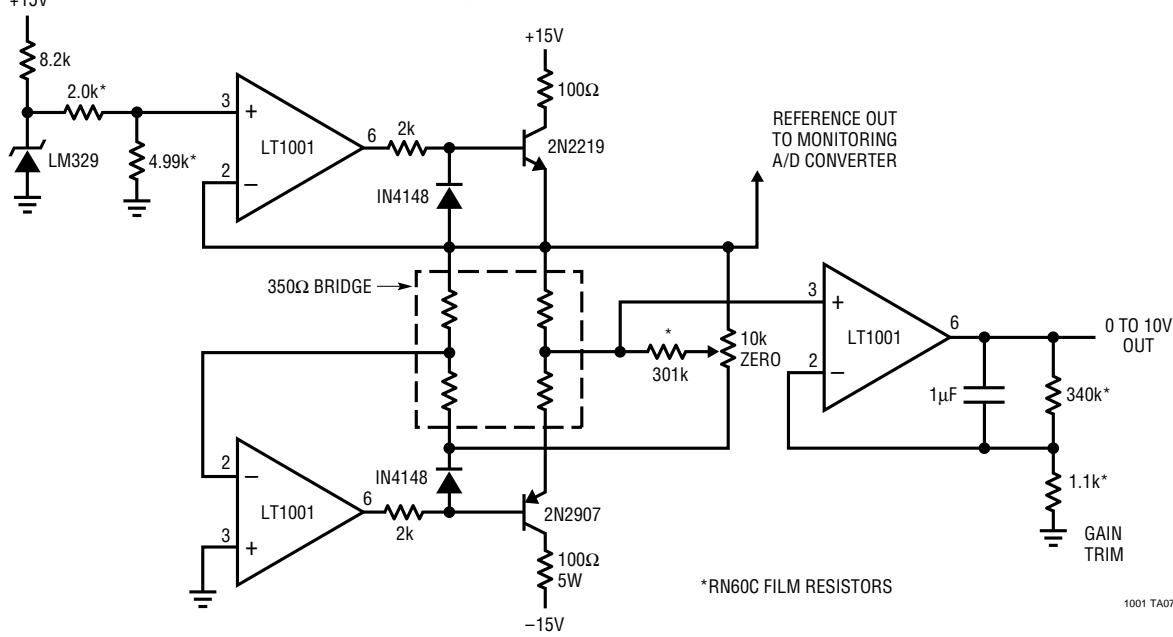
1001 TA05

### Precision Current Sink



1001 TA06

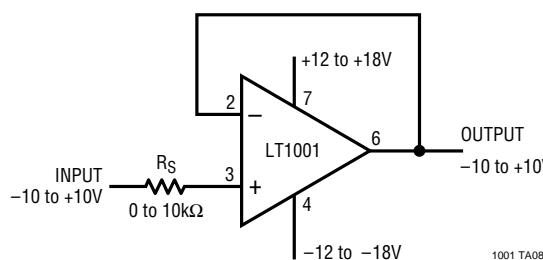
### Strain Gauge Signal Conditioner with Bridge Excitation



\*RN60C FILM RESISTORS

1001 TA07

### Large Signal Voltage Follower With 0.001% Worst-Case Accuracy

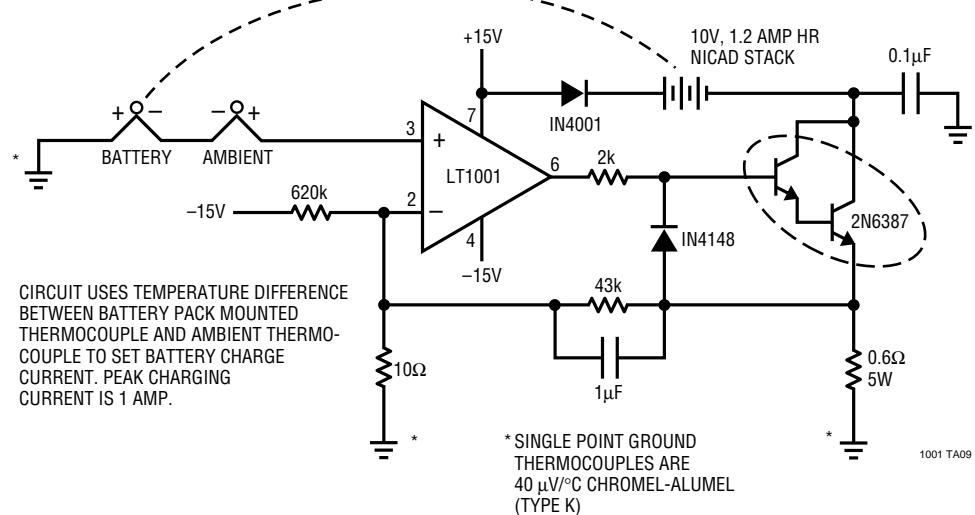


The voltage follower is an ideal example illustrating the overall excellence of the LT1001. The contributing error terms are due to offset voltage, input bias current, voltage gain, common-mode and power-supply

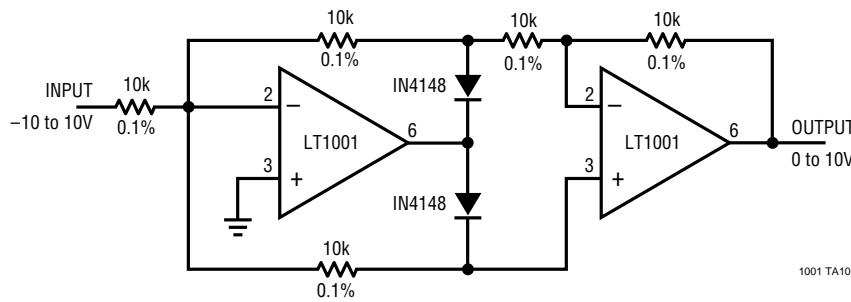
rejections. Worst-case summation of guaranteed specifications is tabulated below.

Error	OUTPUT ACCURACY			
	LT1001AM /883	LT1001C	LT1001AM /883	LT1001C
	25°C Max.	25°C Max.	-55 to 125°C Max.	0 to 70°C Max.
Offset Voltage	15µV	60µV	60µV	110µV
Bias Current	20µV	40µV	40µV	55µV
Common-Mode Rejection	20µV	30µV	30µV	50µV
Power Supply Rejection	18µV	30µV	36µV	42µV
Voltage Gain	22µV	25µV	33µV	40µV
Worst-case Sum	95µV	185µV	199µV	297µV
Percent of Full Scale (=20V)	0.0005%	0.0009%	0.0010%	0.0015%

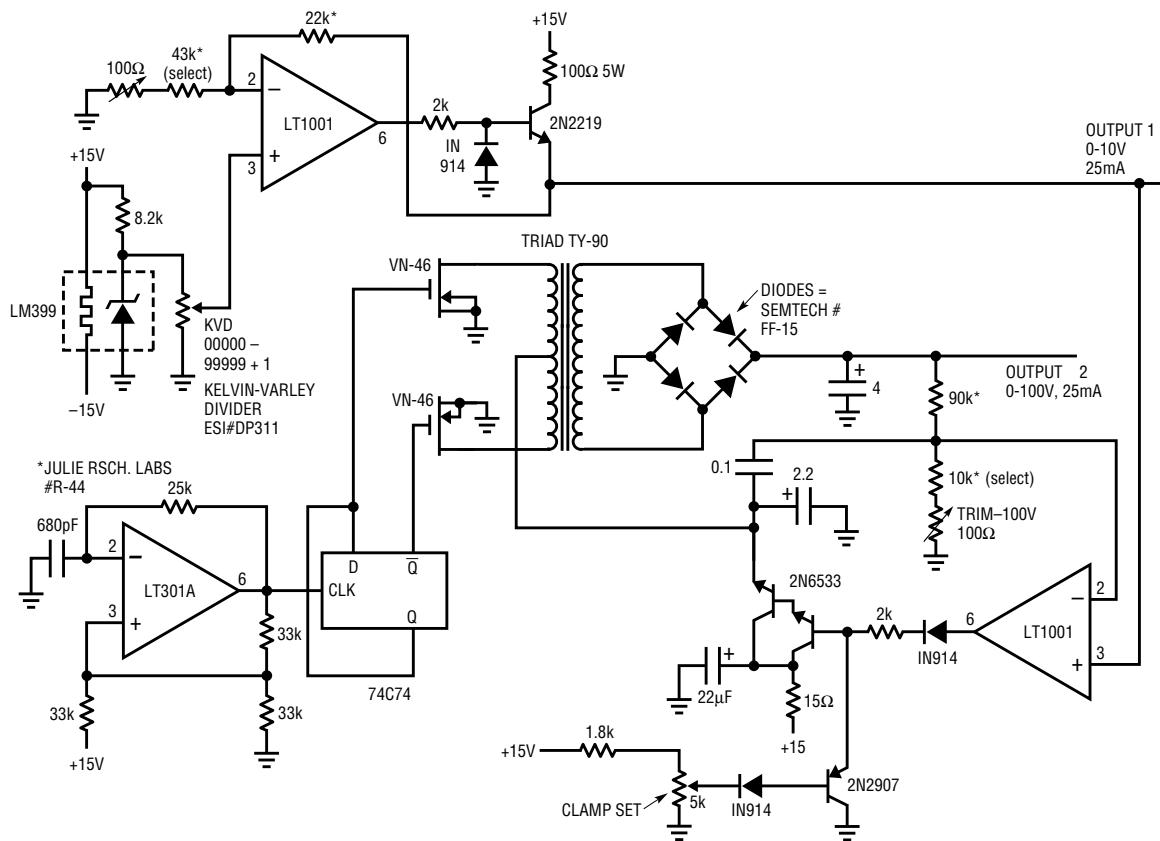
### Thermally Controlled NiCad Charger



### Precision Absolute Value Circuit



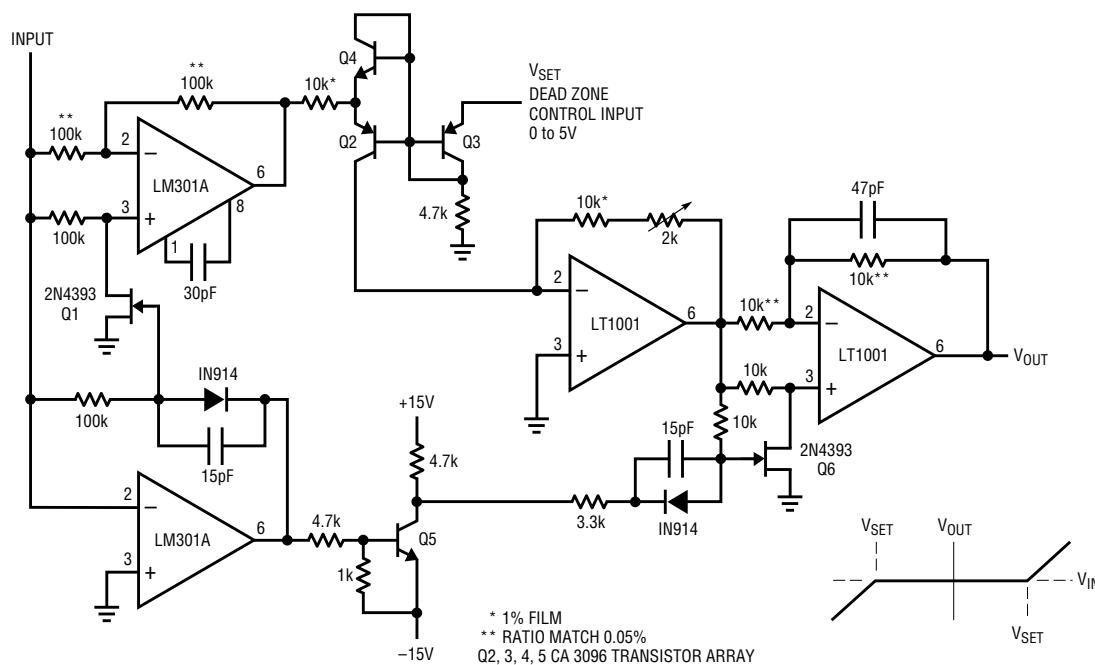
**Precision Power Supply with Two Outputs**  
**(1) 0V to 10V in 100 $\mu$ V STEPS**  
**(2) 0V to 100V in 1mV STEPS**



1001 TA11

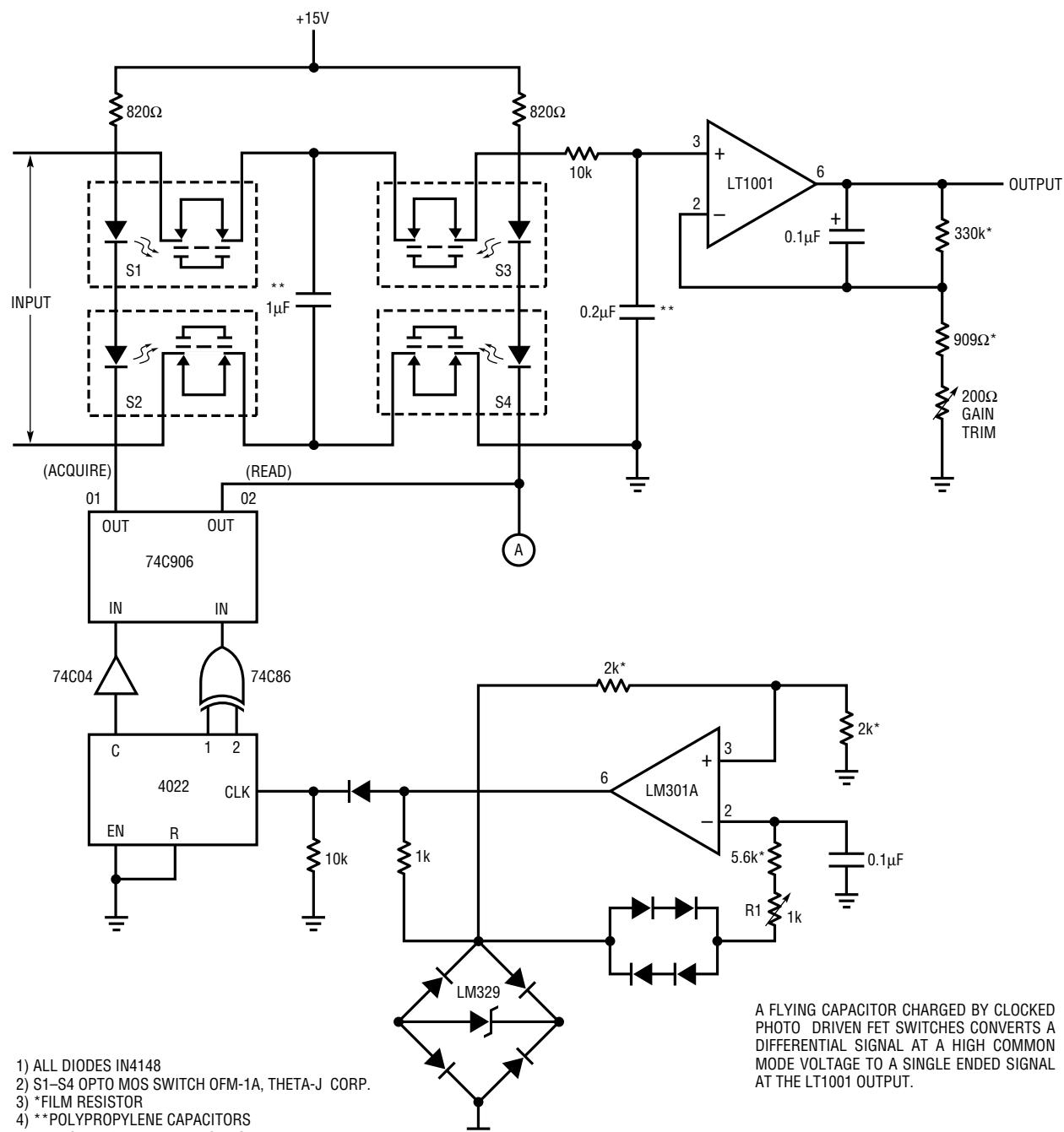
### Dead Zone Generator

BIPOLAR SYMMETRY IS EXCELLENT BECAUSE ONE DEVICE, Q2, SETS BOTH LIMITS



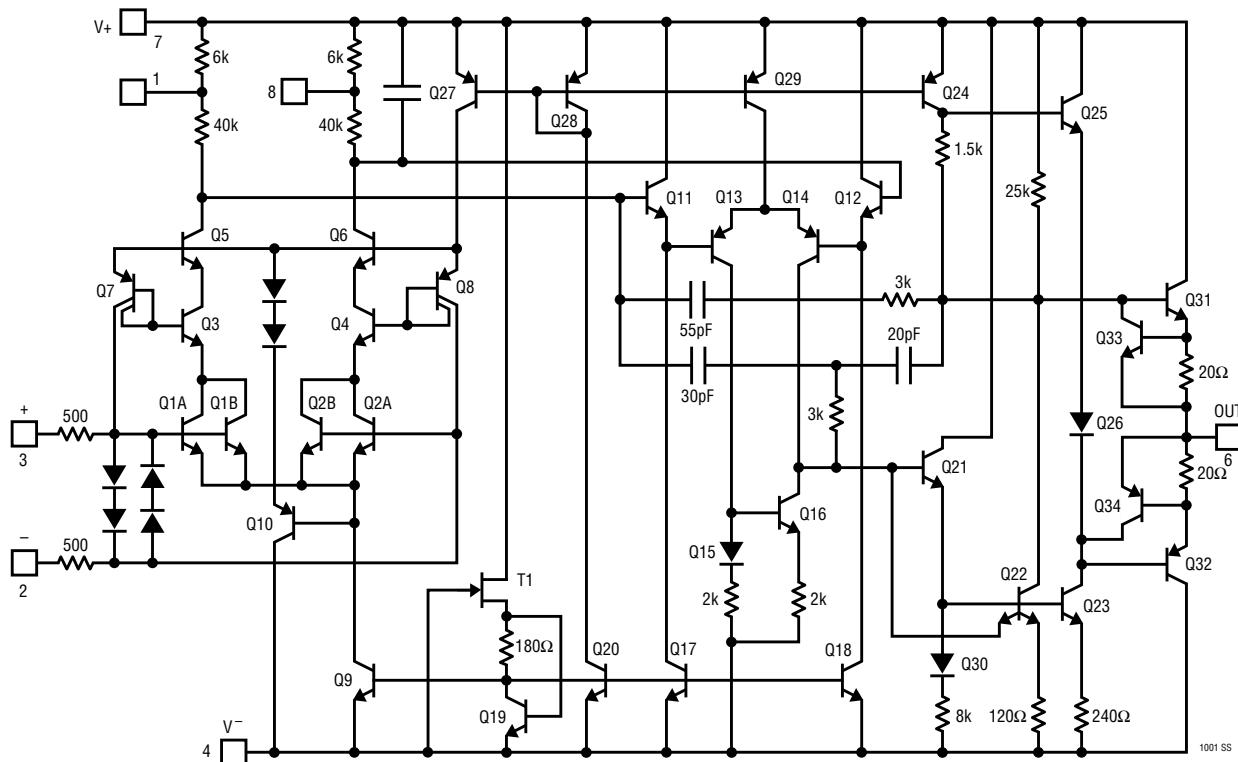
1001 TA12

**Instrumentation Amplifier with  $\pm 300V$   
Common Mode Range and CMRR > 150dB**



1001 TA13

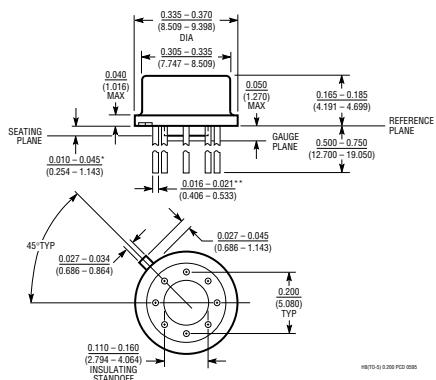
## SCHEMATIC DIAGRAM



## PACKAGE DESCRIPTION

Dimensions in inches (millimeters) unless otherwise noted.

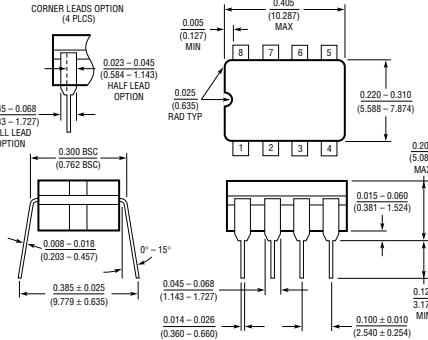
## H Package

8-Lead TO-5 Metal Can (0.200 PCD)  
(LTC DWG # 05-08-1320)

\*LEAD DIAMETER IS UNCONTROLLED BETWEEN THE REFERENCE PLANE  
AND 0.045" BELOW THE REFERENCE PLANE  
\*\*FOR SOLDER DIP LEAD FINISH, LEAD DIAMETER IS 0.016 - 0.024  
\*\*\*INSULATING STANDOFF

$T_{jmax}$	$\theta_{ja}$	$\theta_{jc}$
150°C	150°C/W	45°C/W

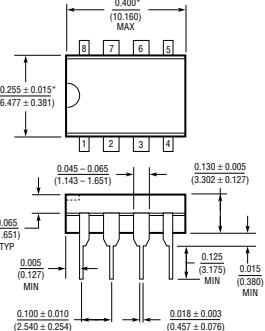
## J8 Package

8-Lead CERDIP (Narrow 0.300, Hermetic)  
(LTC DWG # 05-08-1110)

NOTE: LEAD DIMENSIONS APPLY TO SOLDER DIP/PLATE OR TIN PLATE LEADS.

$T_{jmax}$	$\theta_{ja}$
150°C	100°C/W

## N8 Package

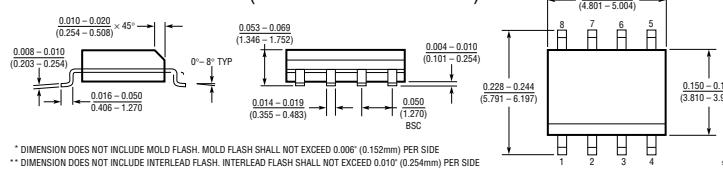
8-Lead PDIP (Narrow 0.300)  
(LTC DWG # 05-08-1510)

\*THESE DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS.  
MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.010 INCH (0.254mm)

$T_{jmax}$	$\theta_{ja}$
150°C	130°C/W

S8 Package  
8-Lead Plastic Small Outline (Narrow 0.150)

(LTC DWG # 05-08-1610)



$T_{jmax}$	$\theta_{ja}$
150°C	150°C/W

\* DIMENSION DOES NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED 0.006" (0.152mm) PER SIDE  
\*\* DIMENSION DOES NOT INCLUDE INTERLEAD FLASH. INTERLEAD FLASH SHALL NOT EXCEED 0.010" (0.254mm) PER SIDE